

High-reliability discrete products and engineering services since 1977

#### NPN SILICON POWER DARLINGTON TRANSISTORS

#### FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

#### MAXIMUM RATINGS

Rating	Symbol	MJ10004	MJ10005	Unit
Collector emitter voltage	V <sub>CEV</sub>	450 500		V
Collector emitter voltage	V <sub>CEX(sus)</sub>	400	450	V
Collector emitter voltage	V <sub>CEO(sus)</sub>	350	400	V
Emitter base voltage	V <sub>EBO</sub>	8.0		V
Collector current-Continuous	Ι <sub>c</sub>	20		А
-Peak	I <sub>см</sub>	30		
Base current	IB	2.5		А
Total power dissipation @ Tc = 25°C		175		W
Total power dissipation @ Tc = 100°C	PD	100		W
Derate above 25°C		1.0		W/°C
Operating and storage temperature range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +200		°C
Thermal resistance, junction to case	Rejc	1.0		°C/W

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise specified)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector emitter sustaining voltage ( $I_c = 250$ mA, $I_B = 0$ , $V_{clamp} = Rated V_{CEO}$ )	MJ10004 MJ10005	V <sub>CEO(sus)</sub>	350 400	-	Vdc
Collector cutoff current ( $V_{CE}$ = Rated $V_{CEV}$ , $R_{BE}$ = 50 $\Omega$ , $T_C$ = 100°C )		Icer	-	5.0	mA
Collector cutoff current $(V_{CEV} = Rated V_{CEV}, V_{BE(off)} = 1.5V)$ $(V_{CEV} = Rated V_{CEV}, V_{BE(off)} = 1.5V, T_C = 150^{\circ}C)$		Icev	-	0.25 5.0	mA
Emitter cutoff current (V <sub>EB</sub> = 2.0V, I <sub>C</sub> = 0)		I <sub>EBO</sub>	-	175	mA
ON CHARACTERISTICS (1)					
DC current gain (I <sub>C</sub> = 5.0A, V <sub>CE</sub> = 5.0V) (I <sub>C</sub> = 10A, V <sub>CE</sub> = 5.0V)		h <sub>FE</sub>	50 40	600 400	-
$\label{eq:constraint} \begin{array}{l} \mbox{Collector emitter saturation voltage} \\ (I_{C} = 10A, I_{B} = 400mA) \\ (I_{C} = 20A, I_{B} = 2.0A) \\ (I_{C} = 10A, I_{B} = 400mA, T_{C} = 100^{\circ}C) \end{array}$		V <sub>CE(sat)</sub>		1.9 3.0 2.0	v
Base-emitter saturation voltage ( $I_c = 10A$ , $I_B = 400mA$ ) ( $I_c = 10A$ , $I_B = 400mA$ , $T_c = 100°C$ )		$V_{\text{BE(sat)}}$	-	2.5 2.5	V



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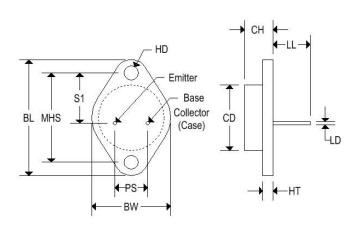
#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise specified)

Characteristic		Symbol	Min	Max	Unit
Diode forward voltage (I <sub>F</sub> = 10A)		V <sub>f</sub>	-	5.0	v
DYNAMIC CHARACTERISTICS	3				
Small signal current gain <sup>(2)</sup> ( $I_c = 1.0A$ , $V_{CE} = 10V$ , $f_{test} = 1MHz$ )		h <sub>fe</sub>	10	-	-
Output capacitance ( $V_{CB} = 10V$ , $I_E = 0$ , $f_{test} = 100$ kHz)		Cob	100	-	pF
SWITCHING CHARACTERISTI	cs	ł			L
Delay time		td	-	0.2	
Rise time	$(V_{cc} = 250V, I_c = 10A,$	tr	-	0.6	
Storage time	$I_{B1}$ = 400mA, V <sub>BE(off)</sub> = 5.0V, t <sub>p</sub> = 50μs, duty cycle ≤ 2%)	ts	-	1.5	μs
Fall time		t <sub>f</sub>	-	0.5	

Note 1: Pulse test: pulse width = 5ms, duty cycle  $\leq$  2%. Note 2:  $f_T$  =  $|\,h_{fe}\,|$  \*  $f_{test}$ 

### MECHANICAL CHARACTERISTICS

Case	TO-3			
Marking	Alpha-numeric			
Polarity	See below			

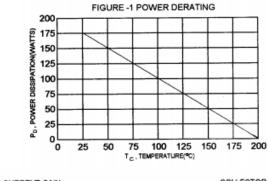


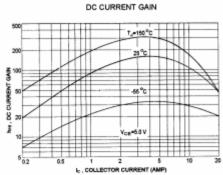
	TO-3			
	Inches		Millim	neters
	Min	Max	Min	Max
CD	-	0.875	-	22.220
СН	0.250	0.380	6.860	9.650
HT	0.060	0.135	1.520	3.430
BW	-	1.050	-	26.670
HD	0.131	0.188	3.330	4.780
LD	0.038	0.043	0.970	1.090
LL	0.312	0.500	7.920	12.700
BL	1.550 REF		39.370 REF	
MHS	1.177	1.197	29.900	30.400
PS	0.420	0.440	10.670	11.180
<b>S</b> 1	0.655	0.675	16.640	17.150

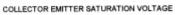


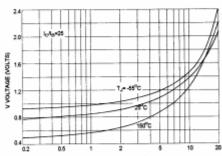
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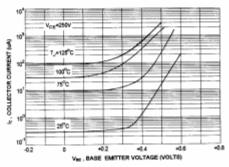




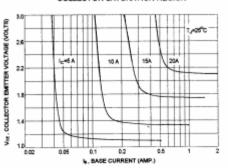


IC . COLLECTOR CURRENT (AMP)

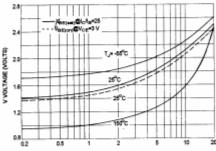




COLLECTOR SATURATION REGION

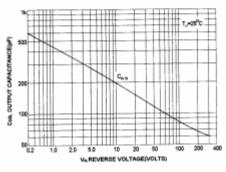


BASE EMITTER VOLTAGE



IC , COLLECTOR CURRENT (AMP)

OUTPUT CAPACITANCES





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